imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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PHOTONIC Silicon Photodiode, Near I.R. Photovoltaic Type PDI-V115-F DETECTORS INC. PACKAGE DIMENSIONS INCH [mm] WINDOW CAP (WELDED) Ø0.325 [8.25] 0.168 [4.26] Ø0.250 [6.35] 0.030 [0.76] 0.075 [1.91] WIRE 0.500 BONDS [12.70] MIN 73° VIEWING Ø0.358 [9.09] 0.200 [5 ANGLE 0.035 ANODE Ø0.018 [0.46] I.R. PASS FILTER-CATHODE Ø0.018 [0.46] HEADER PHOTODIODE 0.110 [2.79] SQUARE Ø0.100 [Ø2.54] ACTIVE AREA **TO-5 HERMETIC CAN PACKAGE** ACTIVE AREA = 5.07 mm² **FEATURES**

- Low noise
- Match to I.R. emitters
- Hermetic package

DESCRIPTION

The PDI-V115-F is a silicon, PIN planar • I.R. pass visible rejection diffused photodiode with NIR pass, visible light rejection optical filter. Ideal for low noise, photovoltaic NIR applications. Packaged in a hermetic TO-5 metal can with a flat window cap

APPLICATIONS

- I.R. detector
- I.R. laser detector
- Photo-interrupters
- Industrial controls

SPECTRAL RESPONSE

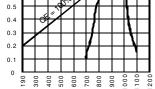
0.7

0.6

RESPONSIVITY (A/W)

	<u>ilat williuuw cap.</u>
ABSOLUTE MAXIMUM R	ATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS		
VBR	Reverse Voltage		100	V		
T _{stg}	Storage Temperature	-55	+100	°C		
To	Operating Temperature Range	-40	+80	°C		
Ts	Soldering Temperature*		+240	°C		
Ι	Light Current		1.0	mA		



WAVELENGTH (nm)

*1/16 inch from case for 3 secs max

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
lsc	Short Circuit Current	H = 100 fc, 2850 K	36	54		mA
ΙD	Dark Current	$H = 0, V_{_{\rm R}} = 10 \text{ V}$		250	450	pА
Rsн	Shunt Resistance	$H = 0, V_{_{\rm R}} = 10 \text{ mV}$	2	5		GΩ
TC Rsh	RSH Temp. Coefficient	$H = 0, V_{_{\rm R}} = 10 \text{ mV}$		-8		%/℃
Cu	Junction Capacitance	$H = 0, V_{_{\rm R}} = 0 V^{**}$		500		pF
λrange	Spectral Application Range	Spot Scan	700		1100	nm
λρ	Spectral Response - Peak	Spot Scan		950		nm
VBR	Breakdown Voltage	l = 10 m A	30	50		V
N EP	Noise Equivalent Power	VR = 10 mV @ Peak		.5x10 ⁻¹⁴		W/ \sqrt{Hz}
tr	Response Time	$RL = 1 K\Omega V_{R} = 0 V$		500		nS

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. ** f = 1 MHz